



500V PNP HIGH VOLTAGE TRANSISTOR IN SOT23

Features

- $BV_{CEO} > -500V$
- I_C = -150mA high Continuous Collector Current
- I_{CM} Up to -500mA Peak Pulse Current
- Excellent h_{FE} Characteristics up to $I_C = -100 mA$
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- An Automotive Compliant Part is Available Under Separate Datasheet (FMMT560Q)

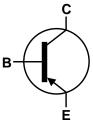
Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight 0.008 grams (Approximate)

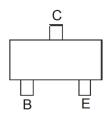




Top View



Device Symbol



Top View Pin-Out

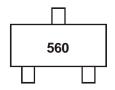
Ordering Information (Note 4)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
FMMT560TA	AEC-Q101	560	7	8	3,000
FMMT560TC	AEC-Q101	560	13	8	10,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



560 = Product Type Marking Code

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Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-500	V
Collector-Emitter Voltage	$V_{\sf CEO}$	-500	V
Emitter-Base Voltage	V_{EBO}	-7	V
Continuous Collector Current	Ic	-150	mA
Peak Pulse Current	I _{CM}	-500	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)	P_{D}	500	mW
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{\theta JA}$	250	°C/W
Thermal Resistance, Junction to Lead (Note 6)		$R_{ heta JL}$	194	°C/W
Operating and Storage Temperature Range	$T_{J_i} T_{STG}$	-55 to +150	°C	

ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge – Machine Model	ESD MM	400	V	С

Notes:

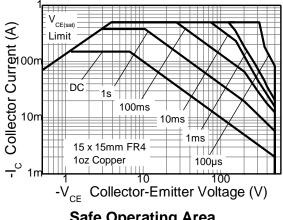
^{5.} For a device mounted with the collector lead on 15mm x 15mm 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

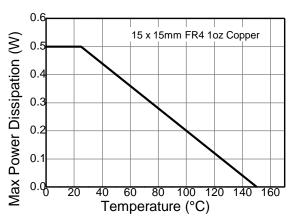
^{6.} Thermal resistance from junction to solder-point (at the end of the collector lead).

^{7.} Refer to JEDEC specification JESD22-A114 and JESD22-A115.

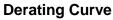


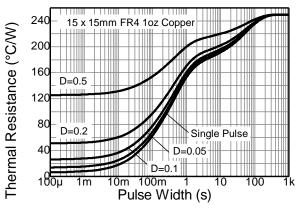
Thermal Characteristics and Derating Information

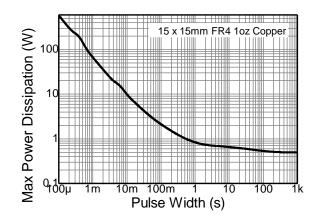




Safe Operating Area







Transient Thermal Impedance

Pulse Power Dissipation

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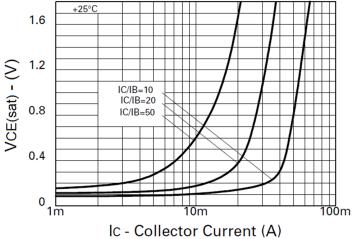
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

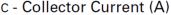
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-500	_		V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 8)	BV _{CEO}	-500	_	_	V	$I_C = -1mA$
Emitter-Base Breakdown Voltage	BV_EBO	-7	_	_	V	$I_E = -100 \mu A$
Collector Cutoff Current	Ісво	_	_	-100	nA	V _{CB} = -500V
Emitter Cutoff Current	I _{EBO}	_	_	-100	nA	$V_{EB} = -5V$
Static Forward Current Transfer Ratio (Note 8)	h _{FE}	100 80 —	_ _ 15	300 300 —	_	$I_C = -1mA$, $V_{CE} = -10V$ $I_C = -50mA$, $V_{CE} = -10V$ $I_C = -100mA$, $V_{CE} = -10V$
Collector-Emitter Saturation Voltage (Note 8)	V _{CE(SAT)}	_	_	-200 -500	mV	$I_C = -20\text{mA}, I_B = -2\text{mA}$ $I_C = -50\text{mA}, I_B = -10\text{mA}$
Base-Emitter Saturation Voltage (Note 8)	V _{BE(SAT)}	_	_	-0.9	V	$I_C = -50 \text{mA}, I_B = -10 \text{mA}$
Base-Emitter Turn-On Voltage (Note 8)	V _{BE(ON)}	_	_	-0.9	V	$I_C = -50 \text{mA}, V_{CE} = -10 \text{V}$
Output Capacitance	C _{OBO}	_	_	8	pF	$V_{CB} = -20V$, $f = 1MHz$
Transition Frequency	f _T	60	_	_	MHz	$V_{CE} = -20V$, $I_C = -10mA$, $f = 50MHz$
Turn-On Time	t _{ON}	_	110	_	ns	$V_{CE} = -100V, I_{C} = -50mA,$
Turn-Off Time	t _{OFF}	_	1.5	_	μs	$I_{B1} = -5mA$, $I_{B2} = 10mA$

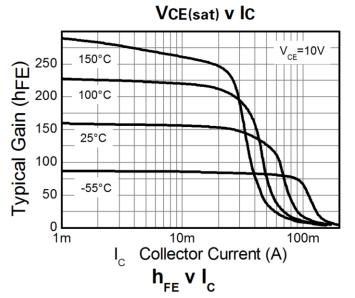
Note: 8. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%

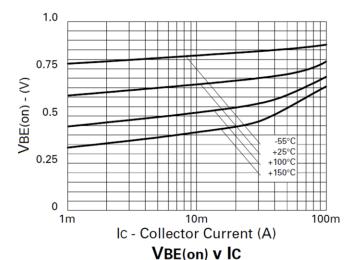


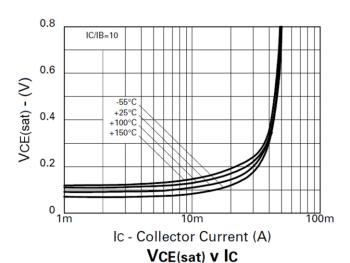
Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

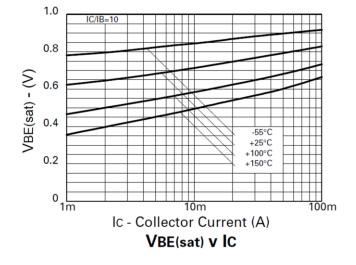










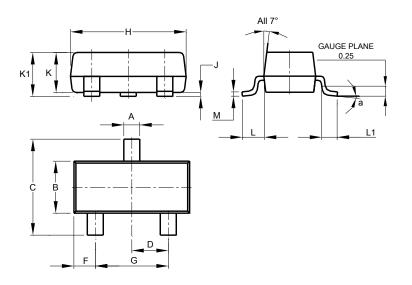




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23

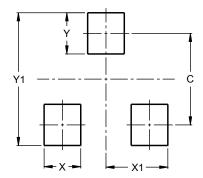


SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
7	0.013	0.10	0.05		
K	0.890	1.00	0.975		
K1	0.903	1.10	1.025		
L	0.45	0.61	0.55		
L1	0.25	0.55	0.40		
М	0.085	0.150	0.110		
а	0°	8°	_		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.



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